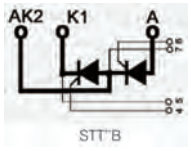
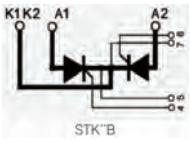
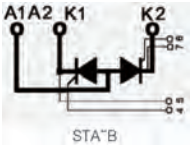
STT49GKXXB

Thyristor-Thyristor Modules



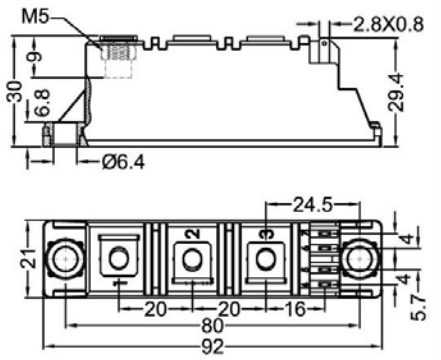






Type	V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V
STT49GK08B	900	800
STT49GK12B	1300	1200
STT49GK14B	1500	1400
STT49GK16B	1700	1600
STT49GK18B	1900	1800

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions		Maximum Ratings	Unit
I_{TRMS}, I_{FRMS} I_{TAVM}, I_{FAVM}	$T_{VJ}=T_{VJM}$ $T_C=85^oC$; 180° sine		76 49	A
I_{TSM}, I_{FSM}	$T_{VJ}=45^oC$ $V_R=0$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	1150 1230	A
	$T_{VJ}=T_{VJM}$ $V_R=0$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	1000 1070	
$\int i^2dt$	$T_{VJ}=45^oC$ $V_R=0$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	6600 6280	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	5000 4750	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ f=50Hz, t_p=200us $V_D=2/3V_{DRM}$ I_G=0.45A di_G/dt=0.45A/us	repetitive, $I_T=150A$ non repetitive, $I_T=I_{TAVM}$	150 500	A/us
$(dv/dt)_{cr}$	$T_{VJ}=T_{VJM}$; $R_{GK}=\infty$; method 1 (linear	$V_{DR}=2/3V_{DRM}$ voltage rise)	1000	V/us
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$	t_p=30us t_p=300us	10 5	W
P_{GAV}			0.5	W
V_{RGM}			10	V
T_{VJ} T_{VJM} T_{stg}			-40...+125 125 -40...+125	°C
V_{ISOL}	50/60Hz, RMS $I_{ISOL}\leq$1mA	t=1min t=1s	3000 3600	V~
M_d	Mounting torque (M5) Terminal connection torque (M5)		2.5-4.0/22-35 2.5-4.0/22-35	Nm/lb.in.
Weight	Typical		110	g

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Thyristor-Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_{RRM}, I_{DRM}	$T_{VJ}=T_{VJM}$; $V_R=V_{RRM}$; $V_D=V_{DRM}$	5	mA
V_{TM}	I_{TM}=150A; T_{VJ}=25°C	1.65	V
V_{TO}	For power-loss calculations only (T_{VJ}=125°C)	0.85	V
r_T		5.3	mΩ
V_{GT}	V_D=6V; T_{VJ}=25°C T_{VJ}=-40°C	1.5 1.6	V
I_{GT}	V_D=6V; T_{VJ}=25°C T_{VJ}=-40°C	100 200	mA
V_{GD}	$T_{VJ}=T_{VJM}$; V_D=2/3V_{DRM}	0.2	V
I_{GD}		10	mA
I_L	T_{VJ}=25°C; t_p=10us; V_D=6V I_G=0.45A; di_G/dt=0.45A/us	450	mA
I_H	T_{VJ}=25°C; V_D=6V; R_{GK}=∞	200	mA
t_{gd}	T_{VJ}=25°C; V_D=1/2V_{DRM} I_G=0.45A; di_G/dt=0.45A/us	2	us
t_q	$T_{VJ}=T_{VJM}$; I_T=120A; t_p=200us; -di/dt=10A/us typ. V_R=100V; dv/dt=20V/us; V_D=2/3V_{DRM}	150	us
Q_S	$T_{VJ}=T_{VJM}$; I_T, I_F=50A; -di/dt=0.64A/us	90	uC
I_{RM}		11	A
R_{thJC}	per thyristor/diode; DC current per module	0.53 0.265	K/W
R_{thJK}	per thyristor/diode; DC current per module	0.73 0.365	K/W
ds	Creeping distance on surface	12.7	mm
d_A	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s^2

FEATURES
* International standard package
* Copper base plate
* Glass passivated chips
* Isolation voltage 3600 V~
* UL file NO.E310749
* RoHS compliant

APPLICATIONS
* DC motor control
* Softstart AC motor controller
* Light, heat and temperature control

ADVANTAGES
* Space and weight savings
* Simple mounting with two screws
* Improved temperature and power cycling
* Reduced protection circuits

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Thyristor-Thyristor Modules

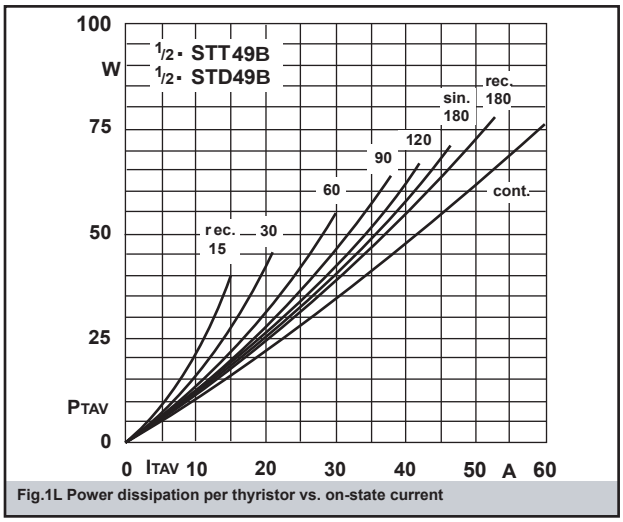


Fig.1L Power dissipation per thyristor vs. on-state current

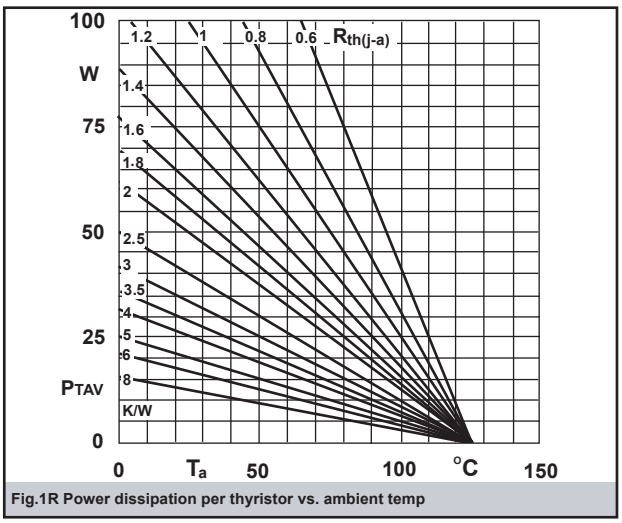


Fig.1R Power dissipation per thyristor vs. ambient temp

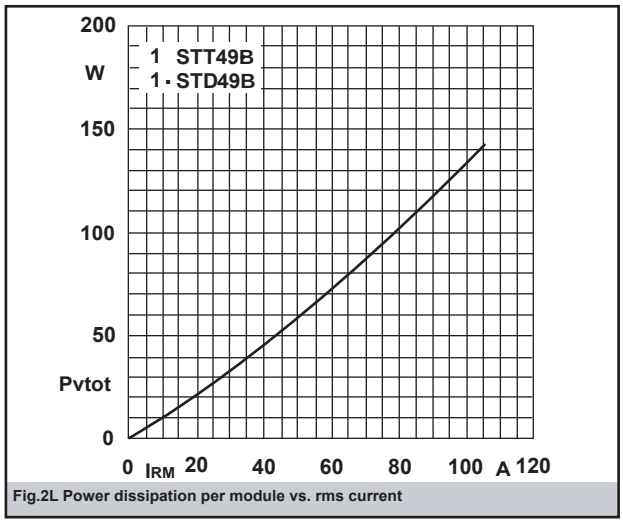


Fig.2L Power dissipation per module vs. rms current

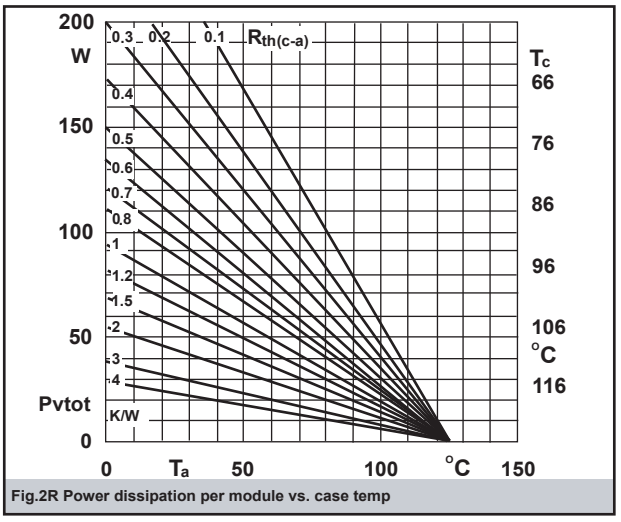


Fig.2R Power dissipation per module vs. case temp

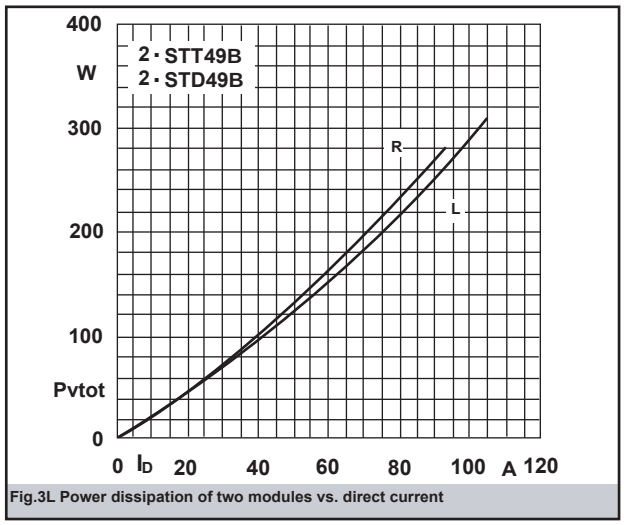


Fig.3L Power dissipation of two modules vs. direct current

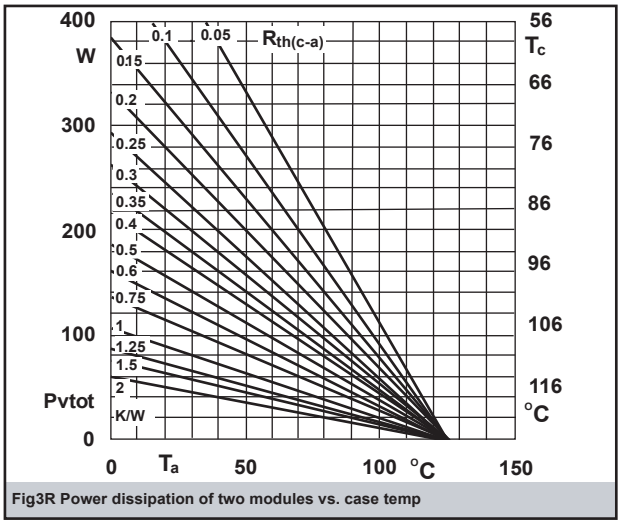


Fig3R Power dissipation of two modules vs. case temp

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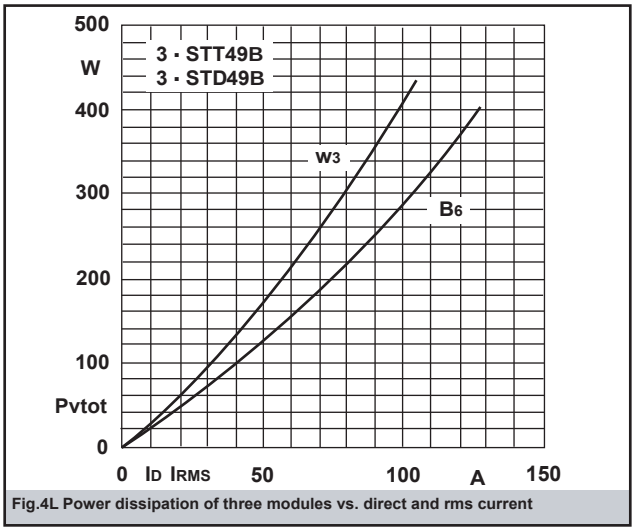


Fig.4L Power dissipation of three modules vs. direct and rms current

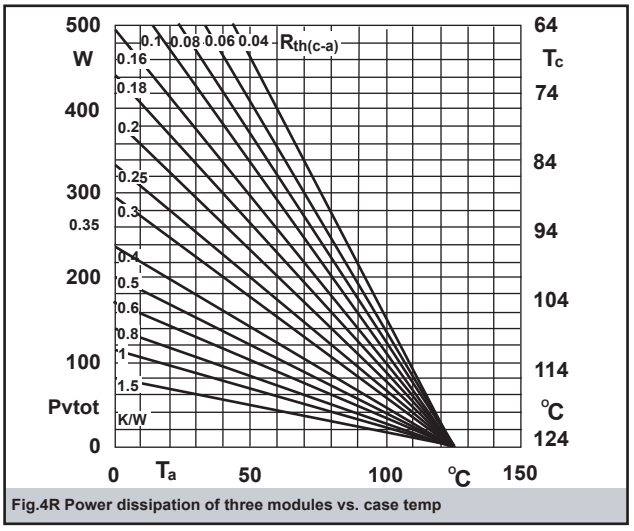


Fig.4R Power dissipation of three modules vs. case temp

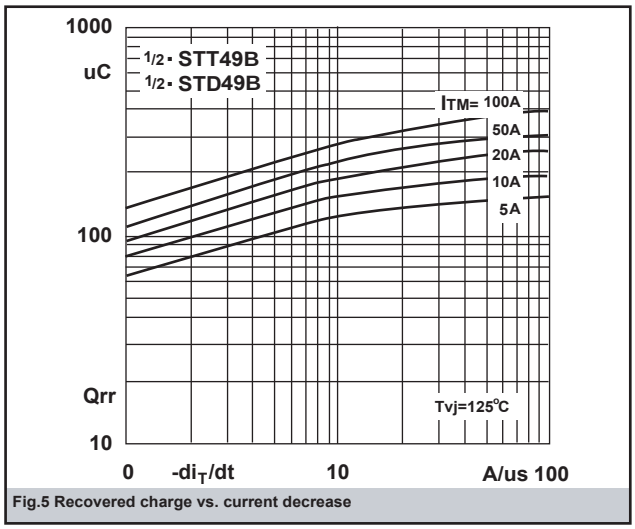


Fig.5 Recovered charge vs. current decrease

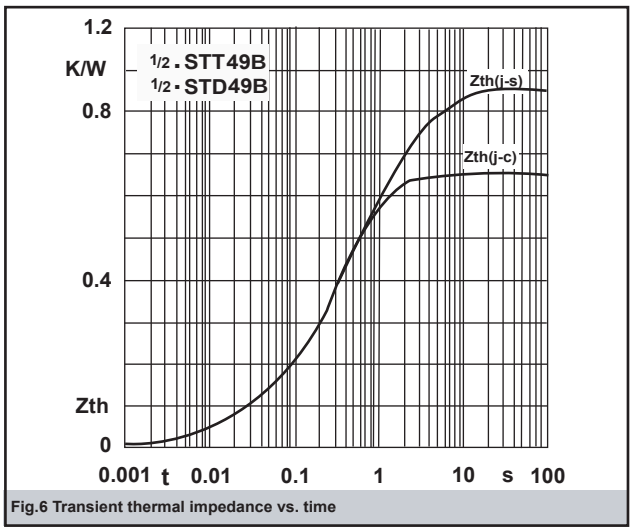


Fig.6 Transient thermal impedance vs. time

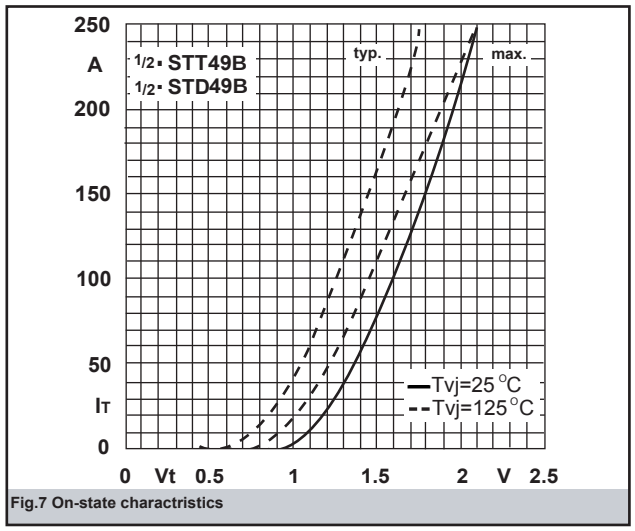


Fig.7 On-state charactristics

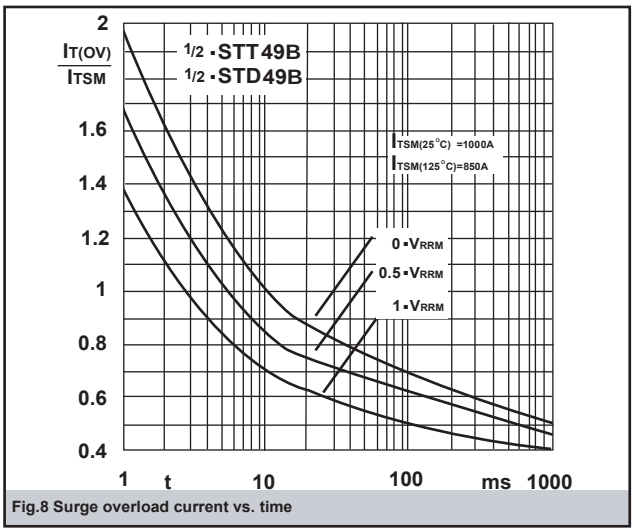


Fig.8 Surge overload current vs. time

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